FGW50XS65

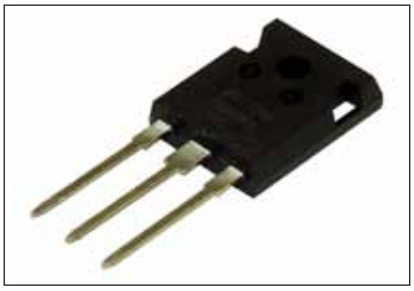
Discrete IGBT (XS-series)
650V / 50A

Features

Low power loss
Low switching surge and noise
High reliability, high ruggedness

Applications

Uninterruptible power supply
PV Power coditionner
Inverter welding machine



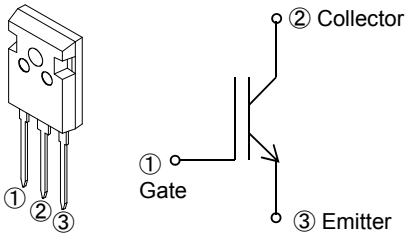
Maximum Ratings and Characteristics

● **Absolute Maximum Ratings at T_{vj} = 25 °C (unless otherwise specified)**

Parameter	Symbol	Value	Unit	Remarks
Collector-Emitter Voltage	V_{CES}	650	V	
Gate-Emitter Voltage	V_{GES}	± 20	V	
Transient Gate-Emitter Voltage		± 30		t_p < 1 µs
DC Collector Current	$I_{C@25}$	77	A	T_C = 25 °C
	$I_{C@100}$	50	A	T_C = 100 °C
Pulsed Collector Current	I_{CP}	200	A	Note *1
Turn-Off Safe Operating Area	-	200	A	V_{CE} ≤ 650 V T_{vj} ≤ 175 °C
Max. Power Dissipation	P_{tot}	290	W	Tc = 25 °C
Operating Junction Temperature	T_{vj}	-40 ~ +175	°C	
Storage Temperature	T_{stg}	-55 ~ +175	°C	

Note *1 : Pulse width limited by $T_{vj\,max}$.

Equivalent circuit



TO-247-P/TO-247-P2

● **Electrical Characteristics at T_{vj} = 25 °C (unless otherwise specified)**

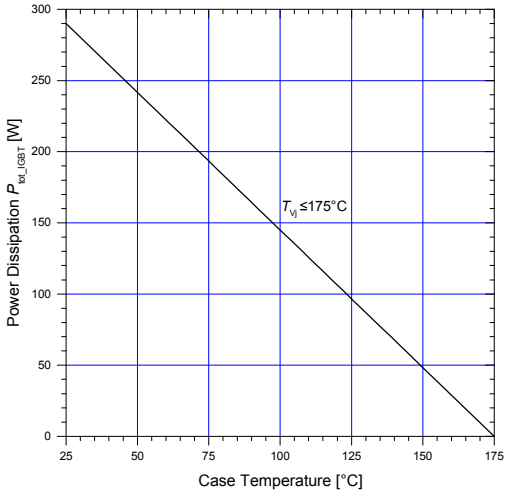
Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Zero Gate Voltage Collector Current	I_{CES}	V_{CE} = 650 V, V_{GE} = 0 V	T_{vj} = 25 °C	-	-	250	µA
			T_{vj} = 175 °C	-	-	2	mA
Gate-Emitter Leakage Current	I_{GES}	V_{CE} = 0 V, V_{GE} = ± 20 V		-	-	200	nA
Gate-Emitter Threshold Voltage	$V_{GE(th)}$	V_{CE} = 20 V, I_C = 50 mA		3.4	4.0	4.6	V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	V_{GE} = 15 V, I_C = 50 A	T_{vj} = 25 °C	-	1.35	1.7	V
			T_{vj} = 125 °C	-	1.5	-	
			T_{vj} = 175 °C	-	1.6	-	
Input Capacitance	C_{ies}	V_{CE} = 25 V, V_{GE} = 0 V, f = 1 MHz		-	4100	-	pF
Output Capacitance	C_{oes}			-	96	-	
Reverse Transfer Capacitance	C_{res}			-	42	-	
Gate Charge	Q_G	V_{CC} = 520 V, I_C = 50 A, V_{GE} = 15 V		-	210	-	nC
Turn-On Delay Time	$t_{d(on)}$	T_{vj} = 25 °C, V_{CC} = 400 V, I_C = 25 A, V_{GE} = 15 V, R_G = 10 Ω, Energy loss include “tail” and FWD reverse recovery.		-	32	-	ns
Rise Time	t_r			-	36	-	
Turn-Off Delay Time	$t_{d(off)}$			-	240	-	
Fall Time	t_f			-	20	-	
Turn-On Energy	E_{on}			-	0.6	-	mJ
Turn-Off Energy	E_{off}			-	0.38	-	
Turn-On Delay Time	$t_{d(on)}$	T_{vj} = 150 °C, V_{CC} = 400 V, I_C = 25 A, V_{GE} = 15 V, R_G = 10 Ω, Energy loss include “tail” and FWD reverse recovery.		-	32	-	ns
Rise Time	t_r			-	24	-	
Turn-Off Delay Time	$t_{d(off)}$			-	280	-	
Fall Time	t_f			-	21	-	
Turn-On Energy	E_{on}			-	0.75	-	mJ
Turn-Off Energy	E_{off}			-	0.5	-	

● Thermal Resistance

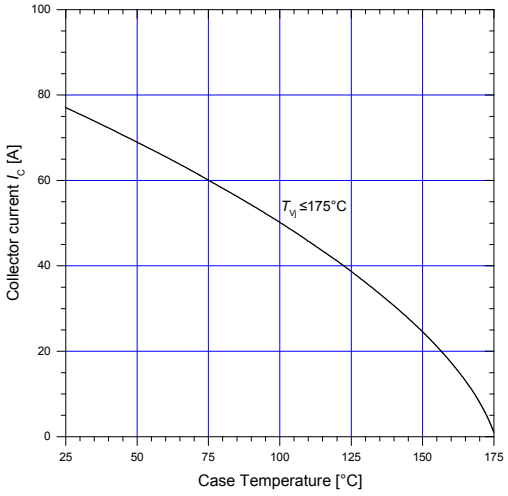
Parameter	Symbol	Min.	Typ.	Max.	Unit
Thermal Resistance, Junction-Ambient	$R_{th(j-a)}$	-	-	50	°C/W
Thermal Resistance, Junction to Case	$R_{th(j-c)}$	-	-	0.518	°C/W

Characteristics (Representative)

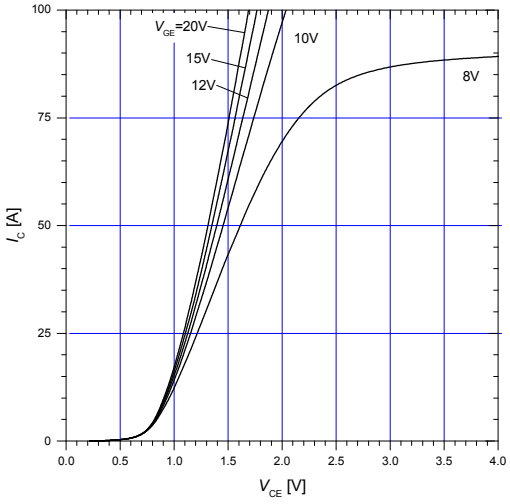
Graph 1
IGBT Power Dissipation vs T_c
T_{vj} ≤ 175°C



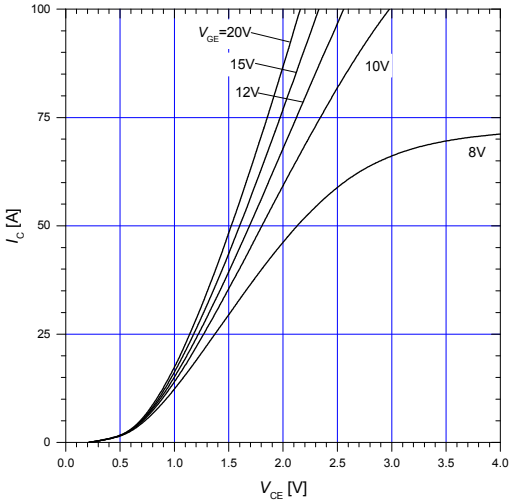
Graph 2
DC Collector Current vs T_c
V_{GE} ≥ +15 V, T_{vj} ≤ 175°C



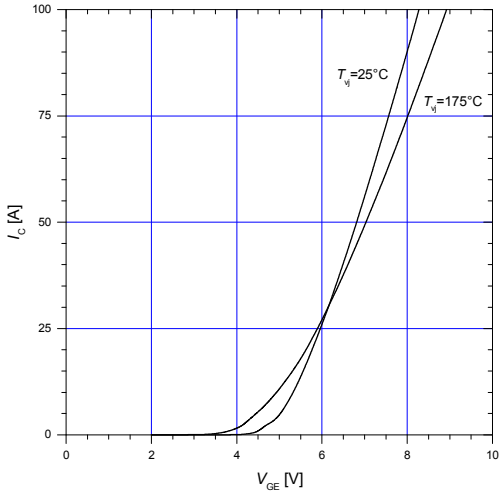
Graph 3
Typical output characteristics
T_{vj} = 25°C



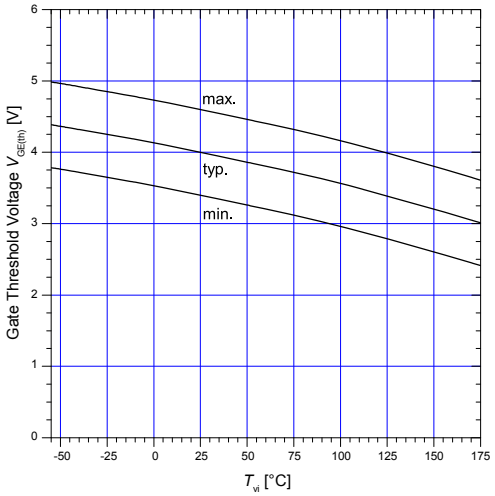
Graph 4
Typical output characteristics
T_{vj} = 175°C



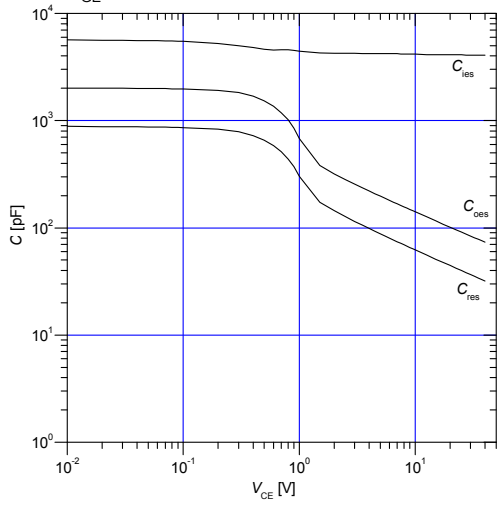
Graph 5
Typical transfer characteristics
V_{CE} = 20 V



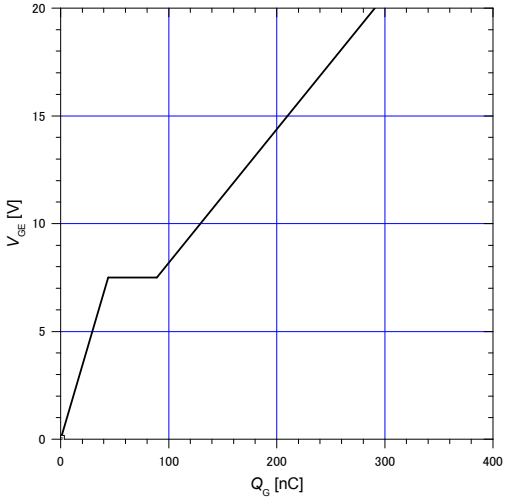
Graph 6
Gate threshold voltage
I_C = 50 mA, V_{CE} = 20 V



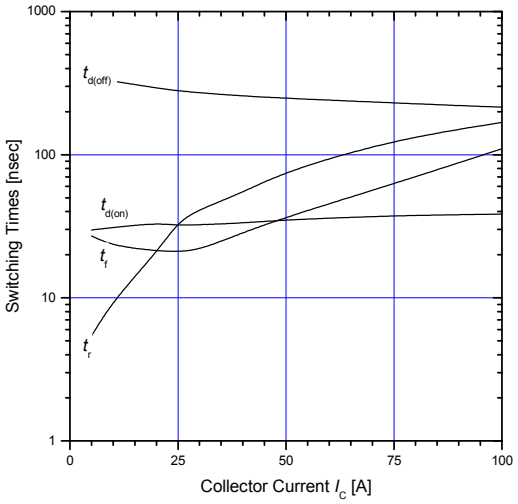
Graph 7
Typical capacitance
V_{GE} = 0 V, f = 1 MHz



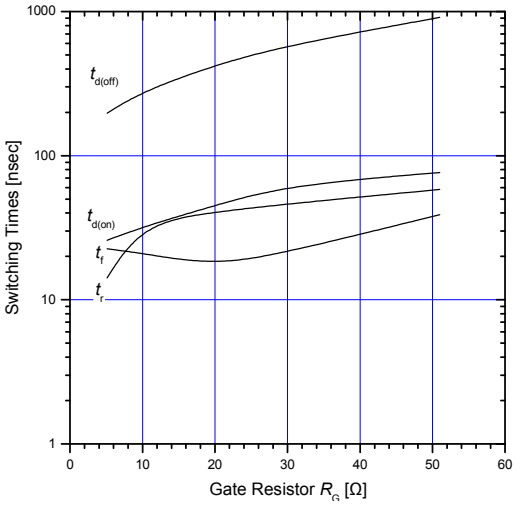
Graph 8
Typical gate charge
I_C = 50 A, V_{CC} = 520 V, T_{vj} = 25°C



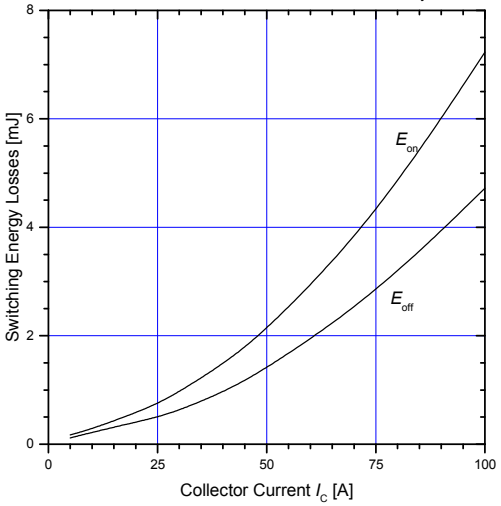
Graph 9
Typical switching times vs. I_C
V_{CC} = 400 V, V_{GE} = 15 V, R_G = 10 Ω, T_{vj} = 150°C



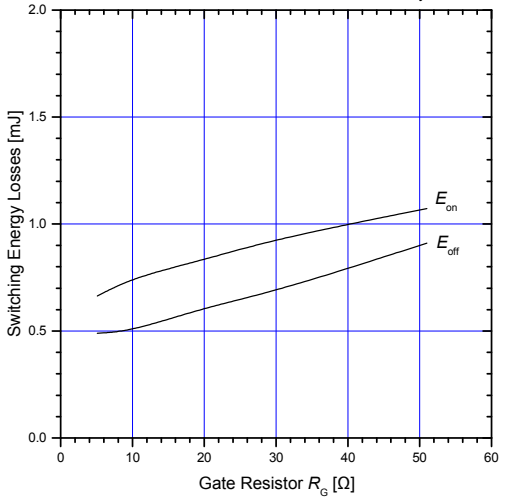
Graph 10
Typical switching times vs. R_G
V_{CC} = 400 V, V_{GE} = 15 V, I_C = 25 A, T_{vj} = 150°C



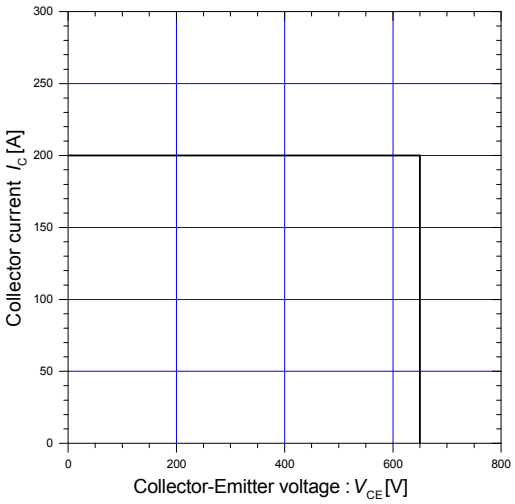
Graph 11
Typical switching losses vs. I_C
V_{CC} = 400 V, V_{GE} = 15 V, R_G = 10 Ω, T_{vj} = 150°C



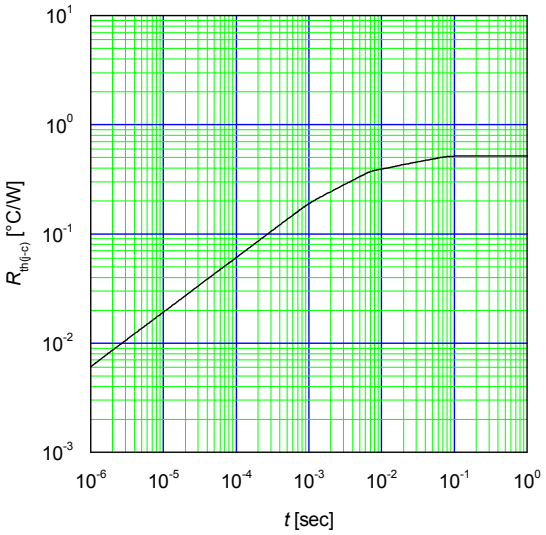
Graph 12
Typical switching losses vs. R_G
V_{CC} = 400 V, V_{GE} = 15 V, I_C = 25 A, T_{vj} = 150°C



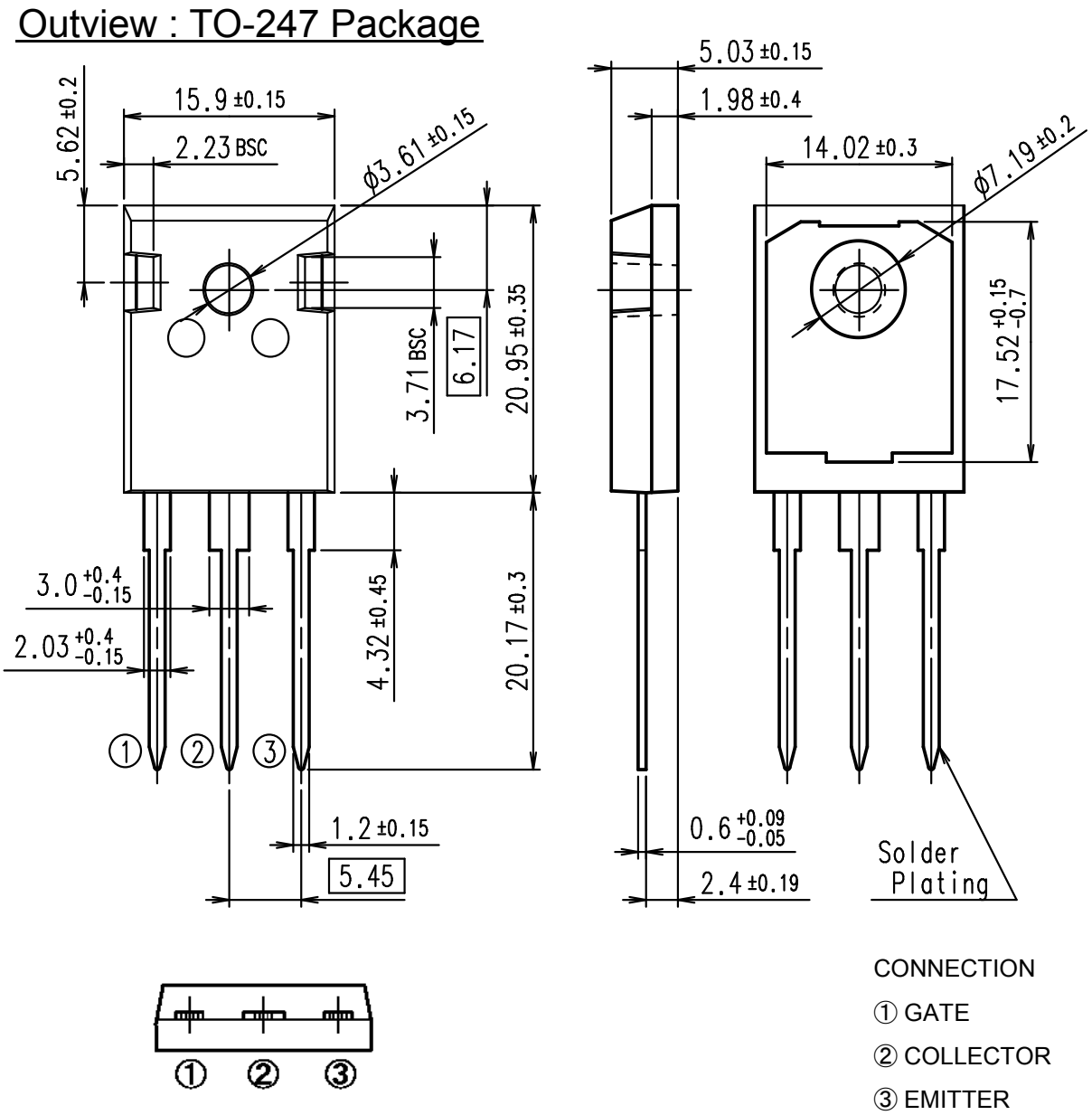
Graph 13
Reverse biased safe operating area
V_{GE} = 15 V / 0 V, R_G = 10 Ω, T_{vj} ≤ 175°C



Graph 14
Transient Thermal Impedance
D = 0



Outline Drawings, mm



CONNECTION

① GATE

② COLLECTOR

③ EMITTER

DIMENSIONS ARE IN MILLIMETERS.

WARNING

1. This Catalog contains the product specifications, characteristics, data, materials, and structures as of September 2018.
The contents are subject to change without notice for specification changes or other reasons. When using a product listed in this Catalog, be sur to obtain the latest specifications.

2. All applications described in this Catalog exemplify the use of Fuji's products for your reference only. No right or license, either express or implied, under any patent, copyright, trade secret or other intellectual property right owned by Fuji Electric Co., Ltd. is (or shall be deemed) granted. Fuji Electric Co., Ltd. makes no representation or warranty, whether express or implied, relating to the infringement or alleged infringement of other's intellectual property rights which may arise from the use of the applications described herein.

3. Although Fuji Electric Co., Ltd. is enhancing product quality and reliability, a small percentage of semiconductor products may become faulty. When using Fuji Electric semiconductor products in your equipment, you are requested to take adequate safety measures to prevent the equipment from causing a physical injury, fire, or other problem if any of the products become faulty. It is recommended to make your design failsafe, flame retardant, and free of malfunction.

4. The products introduced in this Catalog are intended for use in the following electronic and electrical equipment which has normal reliability requirements.
• Computers • OA equipment • Communications equipment (terminal devices) • Measurement equipment
• Machine tools • Audiovisual equipment • Electrical home appliances • Personal equipment • Industrial robots etc.

5. If you need to use a product in this Catalog for equipment requiring higher reliability than normal, such as for the equipment listed below, it is imperative to contact Fuji Electric Co., Ltd. to obtain prior approval. When using these products for such equipment, take adequate measures such as a backup system to prevent the equipment from malfunctioning even if a Fuji's product incorporated in the equipment becomes faulty.
• Transportation equipment (mounted on cars and ships) • Trunk communications equipment
• Traffic-signal control equipment • Gas leakage detectors with an auto-shut-off feature
• Emergency equipment for responding to disasters and anti-burglary devices • Safety devices
• Medical equipment

6. Do not use products in this Catalog for the equipment requiring strict reliability such as the following and equivalents to strategic equipment (without limitation).
• Space equipment • Aeronautic equipment • Nuclear control equipment
• Submarine repeater equipment

8. If you have any question about any portion in this Catalog, ask Fuji Electric Co., Ltd. or its sales agents before using the product.
Neither Fuji Electric Co., Ltd. nor its agents shall be liable for any injury caused by any use of the products not in accordance with instructions set forth herein.

富士電機 Innovating Energy Technology

Technical Information

IGBT Modules

- Please refer to URLs below for futher information about products, application manuals and design support.
- 关于本规格书中没有记载的产品信息，应用手册，技术信息等，请参考以下链接。
- 本データシートに記載されていない製品情報，アプリケーションマニュアル，デザインサポートは以下のURLをご参照下さい。

FUJI ELECTRIC Power Semiconductor WEB site

日本	www.fujielectric.co.jp/products/semiconductor/
Global	www.fujielectric.com/products/semiconductor/
中国	www.fujielectric.com.cn/products/semiconductor/
Europe	www.fujielectric-europe.com/en/power_semiconductor/
North America	www.americas.fujielectric.com/products/semiconductors/

Information

日本

1 半導体総合カタログ	www.fujielectric.co.jp/products/semiconductor/catalog/
2 製品情報	www.fujielectric.co.jp/products/semiconductor/model/
3 アプリケーションマニュアル	www.fujielectric.co.jp/products/semiconductor/model/igbt/application/
4 デザインサポート	www.fujielectric.co.jp/products/semiconductor/model/igbt/technical/
5 マウンティングインストラクション	www.fujielectric.co.jp/products/semiconductor/model/igbt/mounting/
6 IGBT 損失シミュレーションソフト	www.fujielectric.co.jp/products/semiconductor/model/igbt/simulation/
7 富士電機技報	www.fujielectric.co.jp/products/semiconductor/journal/
8 製品のお問い合わせ	www.fujielectric.co.jp/products/semiconductor/contact/
9 改廃のお知らせ	www.fujielectric.co.jp/products/semiconductor/discontinued/

Global

1 Semiconductors General Catalog	www.fujielectric.com/products/semiconductor/catalog/
2 Product Information	www.fujielectric.com/products/semiconductor/model/
3 Application Manuals	www.fujielectric.com/products/semiconductor/model/igbt/application/
4 Design Support	www.fujielectric.com/products/semiconductor/model/igbt/technical/
5 Mounting Instructions	www.fujielectric.com/products/semiconductor/model/igbt/mounting/
6 IGBT Loss Simulation Software	www.fujielectric.com/products/semiconductor/model/igbt/simulation/
7 Fuji Electric Journal	www.fujielectric.com/products/semiconductor/journal/
8 Contact	www.fujielectric.com/contact/
9 Revised and discontinued product information	www.fujielectric.com/products/semiconductor/discontinued/

中国

1 半导体综合目录	www.fujielectric.com.cn/products/semiconductor/catalog/
2 产品信息	www.fujielectric.com.cn/products/semiconductor/model/
3 应用手册	www.fujielectric.com.cn/products/semiconductor/model/igbt/application/
4 技术信息	www.fujielectric.com.cn/products/semiconductor/model/igbt/technical/
5 安装说明书	www.fujielectric.com.cn/products/semiconductor/model/igbt/mounting/
6 IGBT 损耗模拟软件	www.fujielectric.com.cn/products/semiconductor/model/igbt/simulation/
7 富士电机技报	www.fujielectric.com.cn/products/semiconductor/journal/
8 产品咨询	www.fujielectric.com/contact/
9 产品更改和停产信息	www.fujielectric.com.cn/products/semiconductor/discontinued/